Octal D-type transparant latch; 3-state Rev. 05 — 25 March 2010

Product data sheet

1. General description

The 74AHC573; 74AHCT573 is a high-speed Si-gate CMOS device and is pin compatible with Low-power Schottky TTL (LSTTL). It is specified in compliance with JEDEC standard No. 7A.

The 74AHC573; 74AHCT573 consists of eight D-type transparent latches featuring separate D-type inputs for each latch and 3-state true outputs for bus oriented applications. A latch enable input (LE) and an output enable input (\overline{OE}) are common to all latches.

When pin LE is HIGH, data at the Dn inputs enters the latches. In this condition the latches are transparent, i.e. a latch output will change state each time its corresponding Dn input changes. When pin LE is LOW, the latches store the information that is present at the Dn inputs, after a set-up time preceding the HIGH-to-LOW transition of LE.

When pin \overline{OE} is LOW, the contents of the 8 latches are available at the outputs. When pin \overline{OE} is HIGH, the outputs go to the high-impedance OFF-state. Operation of the \overline{OE} input does not affect the state of the latches.

The 74AHC573; 74AHCT573 is functionally identical to the 74AHC373; 74AHCT373, but has a different pin arrangement.

2. Features and benefits

- Balanced propagation delays
- All inputs have a Schmitt trigger action
- Common 3-state output enable input
- Functionally identical to the 74AHC373; 74AHCT373
- Inputs accept voltages higher than V_{CC}
- Input levels:
 - For 74AHC573: CMOS input level
 - For 74AHCT573: TTL input level
- ESD protection:
 - HBM EIA/JESD22-A114E exceeds 2000 V
 - MM EIA/JESD22-A115-A exceeds 200 V
 - CDM EIA/JESD22-C101C exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

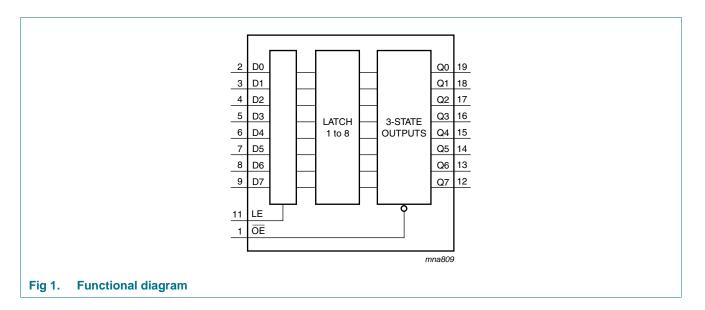




3. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74AHC573				
74AHC573D	–40 °C to +125 °C	SO20	plastic small outline package; 20 leads; body width 7.5 mm	SOT163-1
74AHC573PW	–40 °C to +125 °C	TSSOP20	plastic thin shrink small outline package; 20 leads; body width 4.4 mm	SOT360-1
74AHC573BQ	–40 °C to +125 °C	DHVQFN20	plastic dual in-line compatible thermal enhanced very thin quad flat package no leads; 20 terminals; body $2.5 \times 4.5 \times 0.85$ mm	SOT764-1
74AHCT573				
74AHCT573D	–40 °C to +125 °C	SO20	plastic small outline package; 20 leads; body width 7.5 mm	SOT163-1
74AHCT573PW	–40 °C to +125 °C	TSSOP20	plastic thin shrink small outline package; 20 leads; body width 4.4 mm	SOT360-1
74AHCT573BQ	–40 °C to +125 °C	DHVQFN20	plastic dual in-line compatible thermal enhanced very thin quad flat package no leads; 20 terminals; body $2.5 \times 4.5 \times 0.85$ mm	SOT764-1

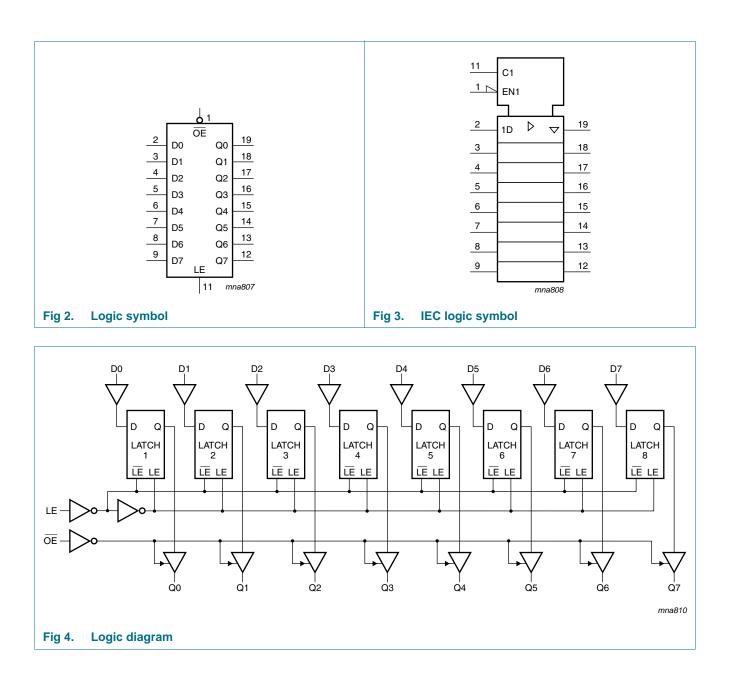
4. Functional diagram



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74AHC573; 74AHCT573

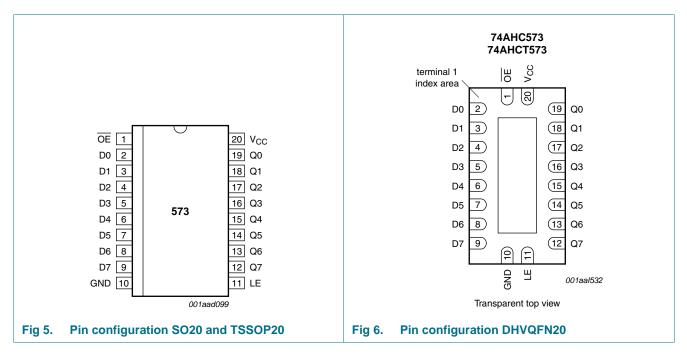
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5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2.	Pin description	
Symbol	Pin	Description
OE	1	output enable input (active LOW)
D0 to D7	2, 3, 4, 5, 6, 7, 8, 9	data input
GND	10	ground (0 V)
LE	11	latch enable (active HIGH)
Q0 to Q7	19, 18, 17, 16, 15, 14, 13,	12 data output
V _{CC}	20	supply voltage

6. Functional description

Table 3.Function table^[1]

Operating mode	Input			Internal latch	Output
	OE	LE	Dn		Qn
Enable and read register (transparent	L	Н	L	L	L
mode)			Н	Н	Н
Latch and read register	L	L	I	L	L
			h	Н	Н
Latch register and disable outputs	Н	L	I	L	Z
			h	Н	Z

[1] H = HIGH voltage level;

h = HIGH voltage level one set-up time prior to the HIGH-to-LOW LE transition;

L = LOW voltage level;

I = LOW voltage level one set-up time prior to the HIGH-to-LOW LE transition;

Z = high-impedance OFF-state.

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7.0	V
VI	input voltage		-0.5	+7.0	V
I _{IK}	input clamping current	V _I < -0.5 V	<u>[1]</u> –20	-	mA
Ι _{ΟΚ}	output clamping current	$V_{\rm O}$ < –0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V	<u>[1]</u> –20	+20	mA
I _O	output current	V_{O} = -0.5 V to (V _{CC} + 0.5 V)	-25	+25	mA
I _{CC}	supply current		-	+75	mA
I _{GND}	ground current		-75	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 \ ^{\circ}C \ to +125 \ ^{\circ}C$	[2] _	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

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8. Recommended operating conditions

Table 5.	Operating conditions					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
74AHC57	3					
V _{CC}	supply voltage		2.0	5.0	5.5	V
VI	input voltage		0	-	5.5	V
Vo	output voltage		0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	V_{CC} = 3.0 V to 3.6 V	-	-	100	ns/V
		V_{CC} = 4.5 V to 5.5 V	-	-	20	ns/V
74AHCT5	73					
V _{CC}	supply voltage		4.5	5.0	5.5	V
VI	input voltage		0	-	5.5	V
Vo	output voltage		0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	V_{CC} = 4.5 V to 5.5 V	-	-	20	ns/V

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		−40 °C	to +85 °C	- 40 °	°C to +′	125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Тур	Max	
74AHC5	73										
VIH	HIGH-level	V _{CC} = 2.0 V	1.5	-	-	1.5	-	1.5	-	-	V
	input voltage	V _{CC} = 3.0 V	2.1	-	-	2.1	-	2.1	-	-	V
		V _{CC} = 5.5 V	3.85	-	-	3.85	-	3.85	-	-	V
V _{IL}	LOW-level	V _{CC} = 2.0 V	-	-	0.5	-	0.5	-	-	0.5	V
	input voltage	V _{CC} = 3.0 V	-	-	0.9	-	0.9	-	-	0.9	V
		V _{CC} = 5.5 V	-	-	1.65	-	1.65	-	-	1.65	V
V _{ОН}	HIGH-level	$V_I = V_{IH} \text{ or } V_{IL}$									
	output voltage	I_{O} = -50 μ A; V_{CC} = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	-	V
		I_{O} = –50 $\mu\text{A};$ V_{CC} = 3.0 V	2.9	3.0	-	2.9	-	2.9	-	-	V
		I_{O} = -50 μ A; V_{CC} = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.58	-	-	2.48	-	2.40	-	-	V
		$I_{O} = -8.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.94	-	-	3.80	-	3.70	-	-	V
V _{OL}	LOW-level	$V_I = V_{IH} \text{ or } V_{IL}$									
	output voltage	$I_0 = 50 \ \mu A; \ V_{CC} = 2.0 \ V$	-	0	0.1	-	0.1	-	-	0.1	V
		$I_0 = 50 \ \mu A; \ V_{CC} = 3.0 \ V$	-	0	0.1	-	0.1	-	-	0.1	V
		$I_O = 50 \ \mu\text{A}; \ V_{CC} = 4.5 \ \text{V}$	-	0	0.1	-	0.1	-	-	0.1	V
		$I_0 = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.36	-	0.44	-	-	0.55	V
		$I_{O} = 8.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.36	-	0.44	-	-	0.55	V

74AHC_AHCT573_5

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	Parameter	ng conditions; voltages are ref Conditions		25 °C			, to +85 °C	_/0 (C to .	125 °C	Unit
Symbol	Falametei	Conditions	Min	Тур	Max	_40 C I	Max	_40 Min	Тур	Max	Unit
I _{OZ}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL};$ $V_{O} = V_{CC} \text{ or GND};$ $V_{CC} = 5.5 \text{ V}$	-		±0.25	-	±2.5	-		±10.0	μA
lı	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 0 V$ to 5.5 V	-	-	0.1	-	1.0	-	-	2.0	μΑ
I _{CC}	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = V_{CC} \text{ or } GND; \ I_{O} = 0 \ A; \\ V_{CC} = 5.5 \ V \end{array}$	-	-	4.0	-	40	-	-	80	μΑ
CI	input capacitance	$V_I = V_{CC}$ or GND	-	3	10	-	10	-	-	10	pF
Co	output capacitance		-	4	-	-	-	-	-	10	pF
74AHCT	573										
V _{IH}	HIGH-level input voltage	V_{CC} = 4.5 V to 5.5 V	2.0	-	-	2.0	-	2.0	-	-	V
V _{IL}	LOW-level input voltage	V_{CC} = 4.5 V to 5.5 V	-	-	0.8	-	0.8	-	-	0.8	V
V _{OH}	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$									
	output voltage	I _O = -50 μA	4.4	4.5	-	4.4	-	4.4	-	-	V
		I _O = -8.0 mA	3.94	-	-	3.80	-	3.70	-	-	V
V _{OL}	LOW-level	V_{I} = V_{IH} or $V_{IL};V_{CC}$ = 4.5 V									
	output voltage	I _O = 50 μA	-	0	0.1	-	0.1	-	-	0.1	V
		I _O = 8.0 mA	-	-	0.36	-	0.44	-	-	0.55	V
I _{OZ}	OFF-state output current		-	-	±0.25	-	±2.5	-	-	±10.0	μA
lı	input leakage current	V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V	-	-	0.1	-	1.0	-	-	2.0	μΑ
I _{CC}	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = V_{CC} \text{ or } GND; \ I_{O} = 0 \ A; \\ V_{CC} = 5.5 \ V \end{array}$	-	-	4.0	-	40	-	-	80	μΑ
Δl _{CC}	additional supply current	per input pin; $V_I = V_{CC} - 2.1 \text{ V}; I_O = 0 \text{ A};$ other pins at V_{CC} or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V	-	-	1.35	-	1.5	-	-	1.5	mA
CI	input capacitance	$V_I = V_{CC} \text{ or } GND$	-	3	10	-	10	-	-	10	pF
Co	output capacitance		-	4	-	-	-	-	-	10	pF

Table 6. Static characteristics ... continued

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10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see <u>Figure 11</u>.

Symbol	Parameter	Conditions			25 °C		−40 °C	to +85 °C	−40 °C	to +125 °C	Unit
				Min	Typ[1]	Max	Min	Max	Min	Max	
74AHC5	573										
t _{pd}	propagation	Dn to Qn; see Figure 7	[2]								
	delay	V_{CC} = 3.0 V to 3.6 V									
		C _L = 15 pF		-	5.5	11.0	1.0	13.0	1.0	14.0	ns
		C _L = 50 pF		-	7.8	14.5	1.0	16.5	1.0	18.5	ns
		V_{CC} = 4.5 V to 5.5 V									
		C _L = 15 pF		-	3.9	6.8	1.0	8.0	1.0	8.5	ns
		C _L = 50 pF		-	5.5	8.8	1.0	10.0	1.0	11.0	ns
		LE to Qn; see Figure 8	[2]								
		V_{CC} = 3.0 V to 3.6 V									
		C _L = 15 pF		-	5.8	11.9	1.0	14.0	1.0	15.0	ns
		C _L = 50 pF		-	8.3	15.4	1.0	17.5	1.0	19.5	ns
		V_{CC} = 4.5 V to 5.5 V									
		C _L = 15 pF		-	4.2	7.7	1.0	9.0	1.0	10.0	ns
		C _L = 50 pF		-	5.9	9.7	1.0	11.0	1.0	12.5	ns
t _{en}	enable time	OE to Qn; see Figure 9	[3]								
		V_{CC} = 3.0 V to 3.6 V									
		C _L = 15 pF		-	5.8	11.5	1.0	13.5	1.0	14.5	ns
		C _L = 50 pF		-	8.3	15.0	1.0	17.0	1.0	19.0	ns
		V_{CC} = 4.5 V to 5.5 V									
		C _L = 15 pF		-	4.4	7.7	1.0	9.0	1.0	10.0	ns
		C _L = 50 pF		-	6.3	9.7	1.0	11.0	1.0	12.5	ns
t _{dis}	disable time	OE to Qn; see Figure 9	[4]								
		V_{CC} = 3.0 V to 3.6 V									
		C _L = 15 pF		-	6.8	11.0	1.0	13.0	1.0	14.0	ns
		C _L = 50 pF		-	9.7	14.5	1.0	16.5	1.0	18.5	ns
		V_{CC} = 4.5 V to 5.5 V									
		C _L = 15 pF		-	4.6	7.7	1.0	9.0	1.0	10.0	ns
		C _L = 50 pF		-	7.4	9.7	1.0	11.0	1.0	12.5	ns
t _W	pulse width	LE HIGH; see Figure 8									
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		5.0	-	-	5.0	-	5.0	-	ns
		$V_{CC} = 4.5 \text{ V} \text{ to } 5.5 \text{ V}$		5.0	-	-	5.0	-	5.0	-	ns
t _{su}	set-up time	Dn to LE; see Figure 10									
		V _{CC} = 3.0 V to 3.6 V		3.5	-	-	3.5	-	3.5	-	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		3.5	-	-	3.5	-	3.5	-	ns

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Symbol	Parameter	Conditions			25 °C		−40 °C	to +85 °C	–40 °C t	o +125 °C	Unit
				Min	Typ[1]	Max	Min	Max	Min	Max	
t _h	hold time	Dn to LE; see Figure 10									
		V_{CC} = 3.0 V to 3.6 V		1.5	-	-	1.5	-	1.5	-	ns
		V_{CC} = 4.5 V to 5.5 V		1.5	-	-	1.5	-	1.5	-	ns
C _{PD}	power dissipation capacitance	$f_i = 1 \text{ MHz};$ V _I = GND to V _{CC}	<u>[5]</u>	-	12	-	-	-	-	-	pF
74AHCT	573; V _{CC} = 4.	5 V to 5.5 V									
t _{pd}	propagation Dn to Qn; see Figure 7		[2]								
	delay	C _L = 15 pF		-	3.5	5.5	1	6.5	1	7.0	ns
		C _L = 50 pF		-	4.9	7.5	1	8.5	1	9.5	ns
		LE to Qn; see Figure 8	[2]								
		C _L = 15 pF		-	3.9	6.0	1	7.0	1	7.5	ns
		C _L = 50 pF		-	5.5	8.5	1	9.5	1	11.0	ns
t _{en}	enable time	OE to Qn; see Figure 9	[3]								
		C _L = 15 pF		-	4.1	6.5	1	7.5	1	8.5	ns
		C _L = 50 pF		-	5.9	8.5	1	10.0	1	11.0	ns
t _{dis}	disable time	OE to Qn; see Figure 9	[4]								
		C _L = 15 pF		-	4.5	6.5	1	7.5	1	8.5	ns
		C _L = 50 pF		-	6.4	9.0	1	10.0	1	11.5	ns
t _W	pulse width	LE HIGH; see Figure 8		5.0	-	-	5.0	-	5.0	-	ns
t _{su}	set-up time	Dn to LE; see Figure 10		3.5	-	-	3.5	-	3.5	-	ns
t _h	hold time	Dn to LE; see Figure 10		1.5	-	-	1.5	-	1.5	-	ns
C _{PD}	power dissipation capacitance	$f_i = 1 \text{ MHz};$ V _I = GND to V _{CC}	<u>[5]</u>	-	18	-	-	-	-	-	pF

Table 7. Dynamic characteristics ... continued

[1] Typical values are measured at nominal supply voltage (V_{CC} = 3.3 V and V_{CC} = 5.0 V).

[2] t_{pd} is the same as t_{PHL} and t_{PLH} .

- [3] t_{en} is the same as t_{PZH} and t_{PZL} .
- [4] t_{dis} is the same as t_{PHZ} and t_{PLZ} .
- [5] C_{PD} is used to determine the dynamic power dissipation (P_D in μW). $\mathsf{P}_{\mathsf{D}} = \mathsf{C}_{\mathsf{P}\mathsf{D}} \times \mathsf{V}_{\mathsf{C}\mathsf{C}}{}^2 \times \mathsf{f}_i \times \mathsf{N} + \Sigma(\mathsf{C}_{\mathsf{L}} \times \mathsf{V}_{\mathsf{C}\mathsf{C}}{}^2 \times \mathsf{f}_o) \text{ where:}$

 f_i = input frequency in MHz;

 $f_o = output frequency in MHz;$

 C_L = output load capacitance in pF;

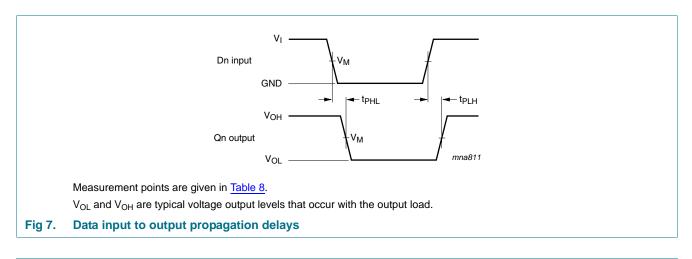
 V_{CC} = supply voltage in V;

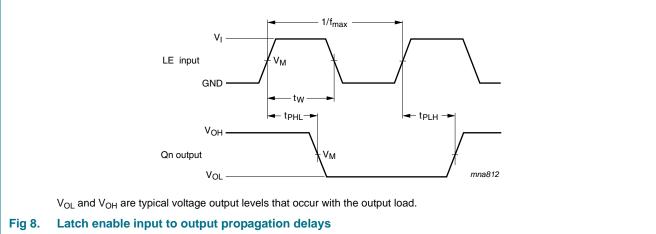
N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

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11. Waveforms

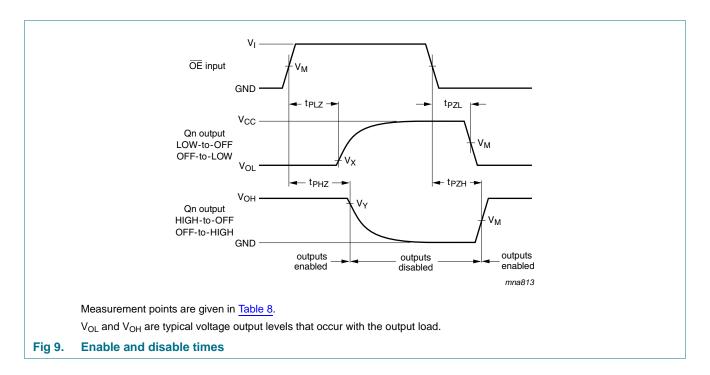




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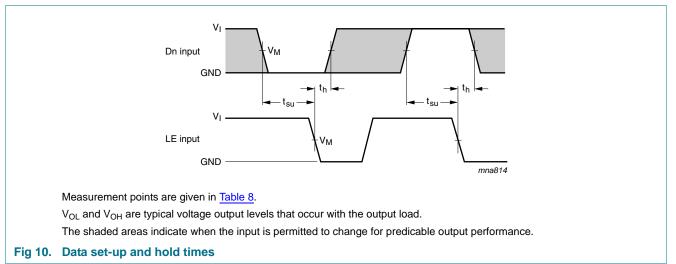


Table 8.Measurement points

Туре	Input	Output					
	V _M	V _M	V _X	V _Y			
74AHC573	$0.5\times V_{CC}$	$0.5\times V_{CC}$	V _{OL} + 0.3 V	V _{OH} – 0.3 V			
74AHCT573	1.5 V	$0.5\times V_{CC}$	V _{OL} + 0.3 V	V _{OH} – 0.3 V			

NXP Semiconductors

74AHC573; 74AHCT573

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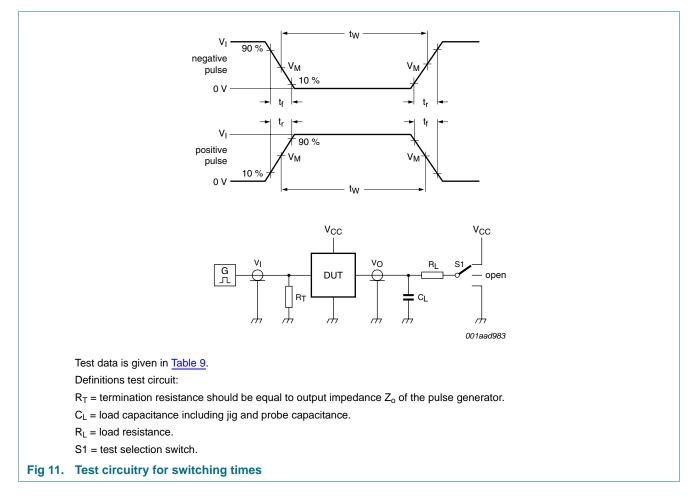


Table 9. Test data

Туре	Input		Load		S1 position		
	VI	t _r , t _f	CL	RL	t _{PHL} , t _{PLH}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
74AHC573	V _{CC}	\leq 3.0 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}
74AHCT573	3.0 V	\leq 3.0 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}



12. Package outline

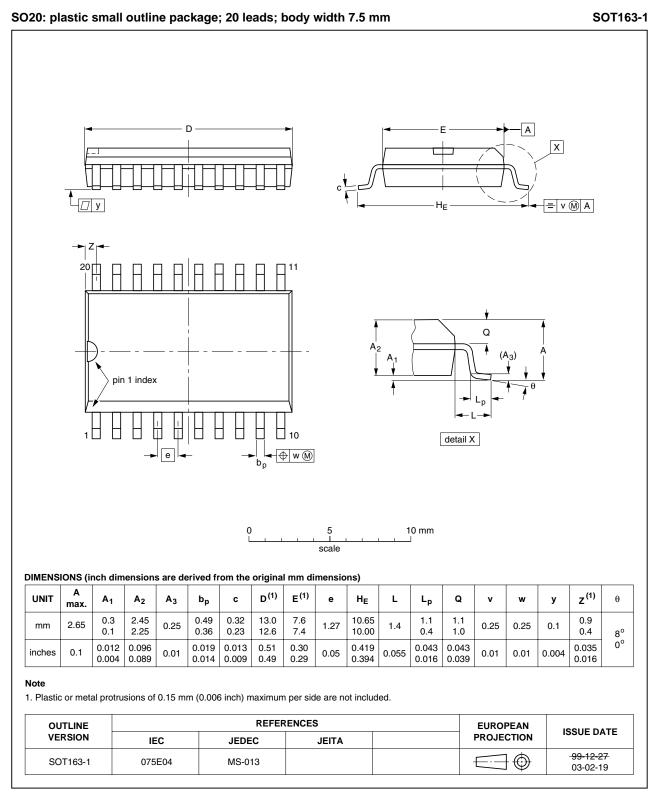


Fig 12. Package outline SOT163-1 (SO20)

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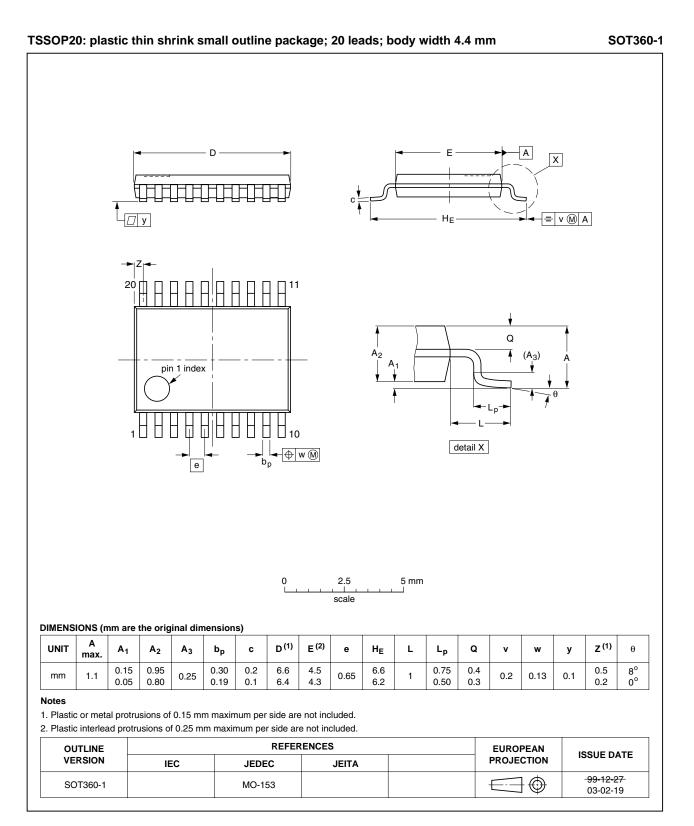
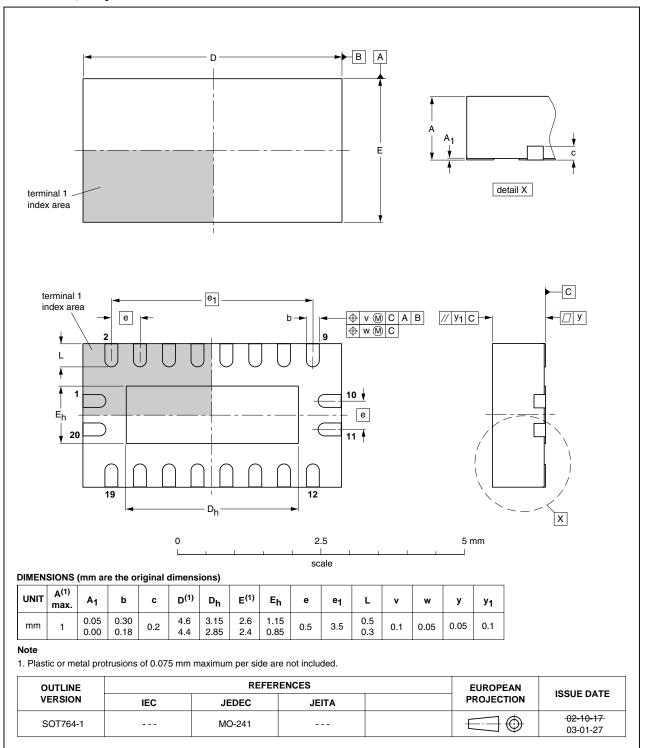


Fig 13. Package outline SOT360-1 (TSSOP20)

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Octal D-type transparant latch; 3-state



DHVQFN20: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 20 terminals; body 2.5 x 4.5 x 0.85 mm SOT764-1

Fig 14. Package outline SOT764-1 (DHVQFN20)



13. Abbreviations

Table 10.	Abbreviations
Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 11. Revision histo	ory			
Document ID	Release date	Data sheet status	Change notice	Supersedes
74AHC_AHCT573_5	20100325	Product data sheet	-	74AHC_AHCT573_4
74AHC_AHCT573_4	20100303	Product data sheet	-	74AHC_AHCT573_3
Modifications:	 Added type n package). 	umbers 74AHC573BQ and 74	AHCT573BQ (DHV0	QFN20 / SOT764-1
74AHC_AHCT573_3	20080424	Product data sheet	-	74AHC_AHCT573_2
74AHC_AHCT573_2	20031208	Product specification	-	74AHC_AHCT573_1
74AHC_AHCT573_1	19990927	Product specification	-	-

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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Product data sheet

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Octal D-type transparant latch; 3-state

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